### features

- High Average Efficiency Over Input Voltage Range Because of Special Switching Topology
- Minimum 200-mA Output Current From an Input Voltage Range of 1.8-V to 3.6-V
- Regulated 3.3-V or 3-V ±4% Output Voltage
- No Inductors Required, Low EMI
- Only Four External Components Required
- 55-μA Quiescent Supply Current
- 0.05-μA Shutdown Current
- Load Disconnected in Shutdown
- Integrated Low Battery and Power Good Detectors
- Evaluation Module Available (TPS60120EVM-142)

### description

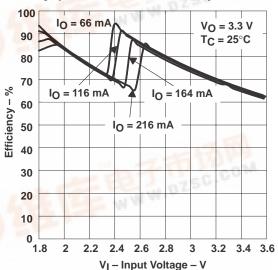
The TPS6012x step-up, regulated charge pumps generate a 3.3-V or 3-V ±4% output voltage from a 1.8-V to 3.6-V input voltage (two alkaline, NiCd, or NiMH batteries). They can deliver an output current of at least 200 mA (100 mA for the TPS60122 and TPS60123), all from a 2-V input. Four external capacitors are needed to build a complete high efficiency dc/dc charge pump converter. To achieve the high efficiency over a wide input voltage range, the charge pump automatically selects between a 1.5x or doubler conversion mode. From a 2-V input, all ICs can start with full load current.

The devices feature the power-saving pulse-skip mode to extend battery life at light loads. TPS60120, TPS60122, and TPS60124 include a low battery comparator. TPS60121, TPS60123, and TPS60125 feature a power-good output. The logic shutdown function reduces the supply current to a maximum of 1  $\mu$ A and disconnects the load from the input. Special current-control circuitry prevents excessive current from being drawn from the battery during start-up. This dc/dc converter requires no inductors, therefore EMI is of low concern. It is available in the small, thermally enhanced 20-pin PowerPAD  $^{\text{TM}}$  package (PWP).

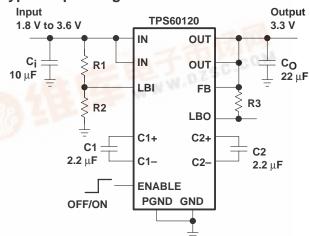
### applications

- Applications Powered by Two Battery Cells
- Portable Instruments
- Battery-Powered Microprocessor Systems
- Miniature Equipment
- Backup-Battery Boost Converters
- PDAs, Organizers, Laptops
- MP-3 Portable Audio Players
- Handheld Instrumentation
- Medical Instruments (e.g., Glucose Meters)
- Cordless Phones

### efficiency (TPS60120, TPS60121)



### typical operating circuit



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





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#### **PWP PACKAGE PWP PACKAGE** (TPS60120, TPS60122, TPS60124) (TPS60121, TPS60123, TPS60125) (TOP VIEW) (TOP VIEW) GND $\square$ 20 ☐ GND GND III 10 20 ☐ GND GND □□ 2 19 GND $\square$ 2 19 ☐ GND ☐☐ GND 3 18 ENABLE \_\_\_\_ 3 ENABLE \_\_\_ 18 □ LBI □ NC FB $\square$ 4 17 FB $\Box$ 4 17 □ PG □ LBO OUT \_\_\_ 5 16 OUT \_\_\_ 5 16 ☐ OUT C1+ □□ 15 □ C2+ C1+ □□ 15 IN $\Box$ 14 IN $\square$ 7 14 7 IN □ IN C1- \_\_\_ 13 C1- | 8 \_\_\_\_ C2-13 \_\_\_ C2− 8 PGND □ 9 12 ☐ PGND PGND \_\_\_ 9 12 ☐ PGND □ PGND PGND □ PGND \_\_\_ 10 11 10 11 Thermal Pad

### **AVAILABLE OPTIONS**

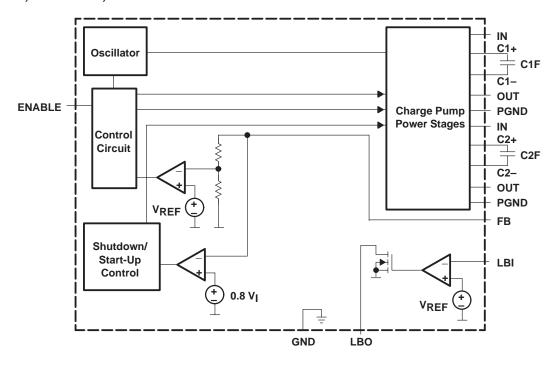
| T <sub>A</sub> | PART NUMBER† | PACKAGE |                                 | DEVICE FEATURES           |                      |  |
|----------------|--------------|---------|---------------------------------|---------------------------|----------------------|--|
|                | TPS60120PWP  | PWP     | 20-Pin thermally enhanced TSSOP | 2-Cell to 3.3 V, 200 mA   | Low battery detector |  |
|                | TPS60121PWP  |         |                                 | 2-Cell to 5.5 V, 200 IIIA | Power good detector  |  |
| -40°C to 85°C  | TPS60122PWP  |         |                                 | 2-Cell to 3.3 V, 100 mA   | Low battery detector |  |
| 40 0 10 00 0   | TPS60123PWP  |         |                                 |                           | Power good detector  |  |
|                | TPS60124PWP  |         |                                 | 2-Cell to 3 V, 200 mA     | Low battery detector |  |
|                | TPS60125PWP  |         |                                 | 2-0611 to 3 V, 200 HIA    | Power good detector  |  |

<sup>&</sup>lt;sup>†</sup> The PWP package is available taped and reeled. Add R suffix to device type (e.g. TPS60120PWPR) to order quantities of 2000 devices per reel.

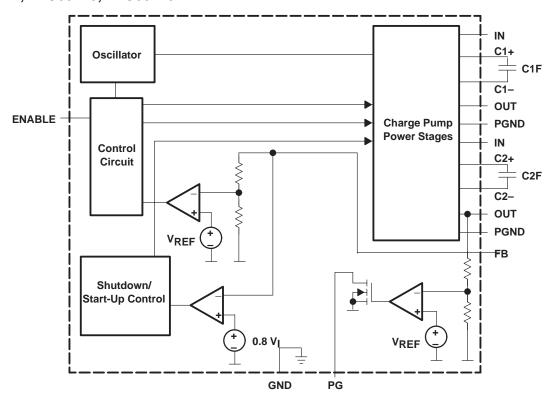


### functional block diagram

### TPS60120, TPS60122, TPS60124



### TPS60121, TPS60123, TPS60125





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### **Terminal Functions**

| TERMI  | NAL             | 1/0 | DESCRIPTION   |
|--------|-----------------|-----|---|
| NAME   | NO.             | 1/0 | DESCRIPTION   |
| C1+    | 6               |     | Positive terminal of the flying capacitor C1  |
| C1-    | 8               |     | Negative terminal of the flying capacitor C1  |
| C2+    | 15              |     | Positive terminal of the flying capacitor C2  |
| C2-    | 13              |     | Negative terminal of the flying capacitor C2  |
| ENABLE | 3               | Ι   | ENABLE input. Connect ENABLE to IN for normal operation. When ENABLE is a logic low, the device turns off and the supply current decreases to 0.05 $\mu$ A. The output is disconnected from the input when the device is placed in shutdown.  |
| FB     | 4               | _   | Feedback input. Connect FB to OUT as close to the load as possible to achieve best regulation. Resistive divider is on the chip to match the internal reference voltage of 1.21 V.  |
| GND    | 1, 2,<br>19, 20 |     | Ground. Analog ground for internal reference and control circuitry. Connect to PGND through a short trace.  |
| IN     | 7,14            | Ι   | Supply input. Connect to an input supply in the 1.8-V to 3.6-V range. Bypass IN to PGND with a $(C_0/2) \mu F$ capacitor. Connect both INs through a short trace.   |
| LBO/PG | 17              | 0   | Low battery detector output or power good output. Open drain output of the low battery or power-good comparator. It can sink 1 mA. A $100$ -k $\Omega$ to $1$ -M $\Omega$ pullup is recommended. Leave terminal unconnected if not used.  |
| LBI/NC | 18              | _   | Low battery detector input (TPS60120/TPS60122/TPS60124 only). The input is compared to the internal 1.21-V reference voltage. Connect terminal to ground if the low-battery detector function is not used. On the TPS60121, TPS60123, and TPS60125, this terminal is not connected. |
| OUT    | 5, 16           | 0   | Regulated power output. Connect both OUT terminals through a short trace and bypass OUT to GND with the output filter capacitor $C_{O}$ .   |
| PGND   | 9–12            |     | Power ground. Charge-pump current flows through this pin. Connect all PGND pins together.   |

### detailed description

### operating principle

The TPS6012x charge pumps provide a regulated 3.3-V or 3-V output from a 1.8-V to 3.6-V input. They are designed for a maximum load current of at least 200 mA or 100 mA, respectively. Designed specifically for space-critical, battery-powered applications, the complete charge pump circuit requires only four external capacitors. The circuit is optimized for efficiency over a wide input voltage range.

The TPS6012x charge pumps consist of an oscillator, a 1.21-V bandgap reference, an internal resistive feedback circuit, an error amplifier, high current MOSFET switches, a shutdown/start-up circuit, a low-battery or power-good comparator, and a control circuit (see the functional block diagram).

The device consists of two single-ended charge pumps. The power stages of the charge pump are automatically configured to amplify the input voltage with a conversion factor of 1.5 or 2. The conversion ratio depends on input voltage and output current. With input voltages lower than approximately 2.4 V, the convertor will run in a voltage doubler mode with a gain of two. With a higher input voltage, the converter operates with a gain of 1.5. This assures high efficiency over the wide input voltage range of a two-cell battery stack and is further described in the *adaptive mode switching* section.

#### adaptive mode switching

The ON-resistance of the MOSFETs that are in the charge path of the flying capacitors is regulated when the charge pump operates in voltage doubler-mode. It is changed depending on the output voltage that is fed back into the control loop. This way, the time-constant during the charging phase can be modified and increased versus a time-constant for fully switched-on MOSFETs. The ON-resistance of both switches and the capacitance of the flying capacitor define the time constant. The MOSFET switches in the discharge path of the charge pump are always fully switched on to their minimum  $r_{DS(on)}$ . With the time-constant during charge phase being larger than the time constant in discharge phase, the voltage on the flying capacitors stabilizes to the lowest possible value necessary to get a stable  $V_{O}$ .



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### adaptive mode switching (continued)

The voltage on the flying capacitors is measured and compared with the supply voltage ( $V_I$ ). If the voltage across the flying capacitors is smaller than half of the supply voltage, then the charge pump switches into the 1.5x conversion-mode. The charge pump switches back from a 1.5x conversion-mode to a voltage doubler mode if the load current in 1.5x conversion-mode can no longer be delivered.

With this control mode the device runs in doubler-mode at low  $V_I$  and in 1.5x conversion-mode at high  $V_I$  to optimize the efficiency. The most desirable doubler mode is automatically selected depending on both  $V_I$  and  $I_L$ . This means that at light loads the device selects the 1.5x conversion-mode already at smaller supply voltages than at heavy loads.

The TPS6012x output voltage is regulated using the *ACTIVE-CYCLE* regulation. An active cycle controlled charge pump utilizes two methods to control the output voltage. At high load currents it varies the on resistances of the internal switches and keeps the ratio ON/OFF time (=frequency) constant. That means the charge pump runs at a fixed frequency. It also keeps the output voltage ripple as low as in linear-mode. At light loads the internal resistance and also the amount of energy transferred per pulse is fixed and the charge pump regulates the voltage by means of a variable ratio of ON-to-OFF time. In this operating point, it runs like a skip mode controlled charge pump with a very high internal resistance, which also enables a low ripple in this operation mode. Since the charge pump does effectively switch at lower frequencies at light loads, it achieves a low quiescent current.

#### pulse-skip mode

In pulse-skip mode the error amplifier disables switching of the power stages when it detects an output higher than the nominal output voltage. The oscillator halts and the IC then skips switching cycles until the output voltage drops below the nominal output voltage. Then the error amplifier reactivates the oscillator and starts switching the power stages again. The pulse-skip regulation mode minimizes operating current because it does not switch continuously and deactivates all functions except bandgap reference, error amplifier, and low-battery/power-good comparator when the output is higher than the nominal output voltage. When switching is disabled from the error amplifier, the load is also isolated from the input. In pulse-skip mode, a special current control circuitry limits the peak current. This assures moderate output voltage ripple and also prevents the device from drawing excessive current spikes out of the battery.

### start-up procedure

During start-up, i.e., when ENABLE is set from logic low to logic high, the output capacitor is charged up with a limited current until the output voltage ( $V_O$ ) reaches  $0.8 \times V_I$ . When the start-up comparator detects this voltage limit, the IC begins switching. This start-up charging of the output capacitor ensures a short start-up time and eliminates the need of a Schottky diode between IN and OUT. The IC starts into a maximum load resistance of  $V_{O(nom)}/I_{O(max)}$ .

#### shutdown

Driving ENABLE low places the device in shutdown mode. This disables all switches, the oscillator, and control logic. The device typically draws  $0.05\,\mu\text{A}$  (1  $\mu\text{A}$  max) of supply current in this mode. Leakage current drawn from the output is as low as 1  $\mu\text{A}$  max. The device exits shutdown once ENABLE is set to a high level. The typical no-load shutdown exit time is 10  $\mu\text{s}$ . When the device is in shutdown, the load is isolated from the input.

### undervoltage lockout and short-circuit current limit

The TPS6012x devices have an undervoltage lockout feature that deactivates the device and places it in shutdown mode when the input voltage falls below the typical threshold voltage of 1.6 V. During a short-circuit condition at the output, the current is limited to 115 mA.



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### low-battery detector (TPS60120, TPS60122, TPS60124)

The internal low-battery comparator trips at 1.21 V  $\pm 5\%$  when the voltage on LBI ramps down. The battery voltage at which the comparator initiates a low battery warning at the LBO output can easily be programmed with a resistive divider as shown in Figure 1. The sum of resistors R1 and R2 is recommended to be in the 100-k $\Omega$  to 1-M $\Omega$  range.

LBO is an open drain output. An external pullup resistor to OUT, in the 100-k $\Omega$  to 1-M $\Omega$  range, is recommended. During start-up, the LBO output signal is invalid for the first 500  $\mu$ s. LBO is high impedance when the device is disabled.

If the low-battery comparator function is not used, connect LBI to ground and leave LBO unconnected.

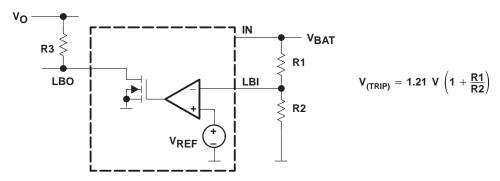


Figure 1. Programming of the Low-Battery Comparator Trip Voltage

Formulas to calculate the resistive divider for low battery detection, with  $V_{LBI} = 1.15 \text{ V} - 1.27 \text{ V}$ :

$$R2 = 1 \text{ M}\Omega \times \frac{V_{LBI}}{V_{Bat}}$$

$$R1 = 1 \text{ M}\Omega - R2$$

Formulas to calculate the minimum and maximum battery voltage that triggers the low battery detector:

$$V_{Bat(min)} = V_{LBI(min)} \times \frac{R1(min) + R2(max)}{R2(max)}$$

$$V_{Bat(max)} = V_{LBI(max)} \times \frac{R1_{(max)} + R2_{(min)}}{R2_{(min)}}$$

Table 1. Recommended Values for the Resistive Divider From the E96 Series ( $\pm 1\%$ ),  $V_{I,BI} = 1.15 \text{ V} - 1.27 \text{ V}$ 

| V <sub>BAT</sub> /V | <b>R1/k</b> Ω | <b>R2/k</b> Ω | VBAT (MIN)/V |        | R2/kΩ VBAT (MIN)/V |       | V <sub>BAT(I</sub> | MAX)/V |
|---------------------|---------------|---------------|--------------|--------|--------------------|-------|--------------------|--------|
| 1.8                 | 357           | 732           | 1.700        | -5.66% | 1.902              | 5.67% |                    |        |
| 1.9                 | 365           | 634           | 1.799        | -5.32% | 2.016              | 6.11% |                    |        |
| 2.0                 | 412           | 634           | 1.883        | -5.86% | 2.112              | 5.6%  |                    |        |
| 2.1                 | 432           | 590           | 1.975        | -5.95% | 2.219              | 5.67% |                    |        |
| 2.2                 | 442           | 536           | 2.080        | -5.45% | 2.338              | 6.27% |                    |        |

Using  $\pm 1\%$  accurate resistors, the total accuracy of the trip voltage is about  $\pm 6\%$ , considering the  $\pm 4\%$  accuracy the integrated voltage reference adds and considering that not every calculated resistor value is available.



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### low-battery detector (TPS60120, TPS60122, TPS60124) (continued)

A 100-nF bypass capacitor should be connected in parallel to R2 if large line transients are expected. These voltage drops can inadvertently trigger the low-battery comparator and produce a wrong low-battery warning signal at the LBO terminal.

### power-good detector (TPS60121, TPS60123, TPS60125)

The PG terminal is an open-drain output that is pulled low when the output is out of regulation. When the output voltage rises to about 90% of its nominal voltage, the power-good output is released. PG is high impedance when the device is disabled. A pullup resistor must be connected between PG and OUT. The pullup resistor should be in the  $100\text{-k}\Omega$  to  $1\text{-M}\Omega$  range. If the power-good function is not used, then PG should remain unconnected.

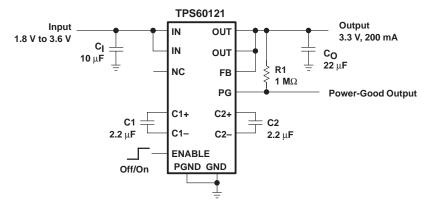


Figure 2. Typical Operating Circuit Using Power-Good Comparator

### absolute maximum ratings (see Note 1)†

| Input voltage range, V <sub>I</sub> (IN, OUT, ENABLE, FB, LBI, LBO/PG) | –0.3 V to 5.5 V  |
|--|--|
| Differential input voltage, V <sub>ID</sub> (C1+, C2+ to GND)          | $-0.3 \text{ V to } (V_{O} + 0.3 \text{ V})$               |
| Differential input voltage, V <sub>ID</sub> (C1–, C2– to GND)          | $-0.3 \text{ V to } (\text{V}_{\text{I}} + 0.3 \text{ V})$ |
| Continuous total power dissipation                                     | . See dissipation rating table                             |
| Continuous output current TPS60120, TPS60121, TPS60124, TPS60125       | 300 mA   |
| Continuous output current TPS60122, TPS60123                           | 150 mA   |
| Storage temperature range, T <sub>stq</sub>                            | –55°C to 150°C   |
| Lead temperature 1,6 mm (1/16 inch) from case for 10s                  | 260°C  |
| Maximum junction temperature, T <sub>J</sub>                           |  |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTE 1:  $V_{(ENABLE)}$ ,  $V_{(LBI)}$ , and  $V_{(LBO/PG)}$  can exceed  $V_{I}$  up to the maximum rated voltage without increasing the leakage current drawn by these inputs.

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### DISSIPATION RATING TABLE 1 FREE-AIR TEMPERATURE (see Figure 3)

| PACKAGE | T <sub>A</sub> ≤ 25°C | DERATING FACTOR             | T <sub>A</sub> = 70°C | T <sub>A</sub> = 85°C |
|---------|-----------------------|-----------------------------|-----------------------|-----------------------|
|         | POWER RATING          | ABOVE T <sub>A</sub> = 25°C | POWER RATING          | POWER RATING          |
| PWP     | 700 mW                | 5.6 mW/°C                   | 448 mW                | 364 mW                |

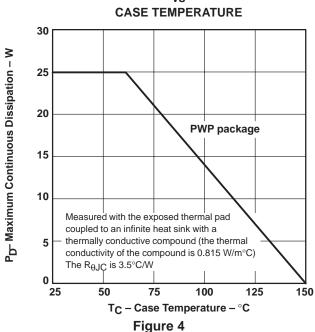
### DISSIPATION RATING TABLE 2 FREE-AIR TEMPERATURE (see Figure 4)

| PACKAGE | T <sub>C</sub> ≤ 62.5°C | DERATING FACTOR               | T <sub>C</sub> = 70°C | T <sub>C</sub> = 85°C |
|---------|-------------------------|-------------------------------|-----------------------|-----------------------|
|         | POWER RATING            | ABOVE T <sub>C</sub> = 62.5°C | POWER RATING          | POWER RATING          |
| PWP     | 25 mW                   | 285.7 mW/°C                   | 22.9 mW               | 18.5 mW               |

# **DISSIPATION DERATING CURVE**† FREE-AIR TEMPERATURE 1400 1200 Pp Dissipation Derating Curve – mW 1000 800 **PWP Package** 600 $R_{\theta JA} = 178^{\circ}C/W$ 400 200 25 100 125 150 T<sub>A</sub> - Free-Air Temperature - °C

Figure 3

# MAXIMUM CONTINUOUS DISSIPATION†



† Dissipation rating tables and figures are provided for maintenance of junction temperature at or below absolute maximum temperature of 150°C. It is recommended not to exceed a junction temperature of 125°C.

### recommended operating conditions

|  | MIN | MAX | UNIT |
|--|-----|-----|------|
| Input voltage, V <sub>I</sub>                  | 1.8 | 3.6 | V    |
| Operating junction temperature, T <sub>J</sub> |     | 125 | °C   |

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# electrical characteristics at C<sub>I</sub> = 10 $\mu$ F, C<sub>1F</sub> = C<sub>2F</sub> = 2.2 $\mu$ F, C<sub>O</sub> = 22 $\mu$ F, T<sub>C</sub> = -40°C to 85°C, V<sub>I</sub> = 2 V, V<sub>FB</sub> = V<sub>O</sub> and V<sub>(ENABLE)</sub> = V<sub>I</sub> (unless otherwise noted)

|                           | PARAMETER                               |   | TEST CONDITIONS   | MIN                  | TYP    | MAX                  | UNIT |
|---------------------------|---|---|---|----------------------|--------|----------------------|------|
| Viv. i s                  | Minimum start up voltage                |   | I <sub>O</sub> = 0  | 1.8                  |        |                      | V    |
| V <sub>I(min)</sub>       | Minimum start-up voltage                | •   | $I_O = I_O(max)$  | 2                    |        |                      | V    |
| V(UVLO)                   | O) Input undervoltage lockout threshold |   | $T_C = 25^{\circ}C$   |                      | 1.6    | 1.8                  | V    |
| I <sub>O(MAX)</sub>       | Maximum continuous                      | TPS60120, TPS60121,<br>TPS60124, TPS60125 |   | 200                  |        |                      | mA   |
| <b>C</b> ( 5.)            | output current                          | TPS60122, TPS60123                        |   | 100                  |        |                      | mA   |
|                           |   | TPS60120,                                 | 1.8 V < V <sub>I</sub> < 2 V,<br>0 < I <sub>O</sub> < I <sub>O</sub> (MAX)/2,<br>T <sub>C</sub> = 0°C to 70°C | 3.17                 |        | 3.43                 |      |
|                           |   | TPS60121,<br>TPS60122,<br>TPS60123        | 2 V < V <sub>I</sub> < 3.3 V,<br>0 < I <sub>O</sub> < I <sub>O</sub> (MAX)                                    | 3.17                 |        | 3.43                 |      |
| V/o                       | Output voltage                          | 11 000120                                 | 3.3 V < V <sub>I</sub> < 3.6 V,<br>0 < I <sub>O</sub> < I <sub>O(MAX)</sub>                                   | 3.17                 |        | 3.47                 | V    |
| Vo                        | Output voltage                          |   | 1.8 V < $V_I$ < 2 V,<br>0 < $I_O$ < $I_{O(MAX)}/2$ ,<br>$I_C$ = 0°C to 70°C                                   | 2.88                 |        | 3.12                 | V    |
|                           |   | TPS60124,<br>TPS60125                     | 2 V < V <sub>I</sub> < 3.3 V,<br>0 < I <sub>O</sub> < I <sub>O</sub> (MAX)                                    | 2.88                 |        | 3.12                 |      |
|                           |   |   | 3.3 V < V <sub>I</sub> < 3.6 V,<br>0 < I <sub>O</sub> < I <sub>O</sub> (MAX)                                  | 2.88                 |        | 3.3                  |      |
| I <sub>lkg</sub> (OUT)    | Output leakage current                  |   | $V_{I} = 2.4 \text{ V}, V_{(ENABLE)} = 0 \text{ V}$   |                      |        | 1                    | μΑ   |
| $I_Q$                     | Quiescent current (no-loa               | ad input current)                         | V <sub>I</sub> = 2.4 V  |                      | 55     | 90                   | μΑ   |
| IQ(SDN)                   | Shutdown supply current                 |   | $V_{I} = 2.4 \text{ V}, V_{(ENABLE)} = 0 \text{ V}$   |                      | 0.05   | 1                    | μΑ   |
| fOSC(INT)                 | Internal switching frequer              | ncy                                       | V <sub>I</sub> = 2.4 V  | 210                  | 320    | 450                  | kHz  |
| $V_{IL}$                  | Enable input voltage low                |   | V <sub>I</sub> = 1.8 V  |                      |        | 0.3 x V <sub>I</sub> | V    |
| $V_{IH}$                  | Enable input voltage high               | 1   | V <sub>I</sub> = 3.6 V  | 0.7 x V <sub>I</sub> |        |                      | V    |
| l <sub>lkg</sub> (ENABLE) | Enable input leakage cur                | rent                                      | V(ENABLE) = VGND or VI  |                      | 0.01   | 0.1                  | μΑ   |
|                           | Output load regulation                  |   | $V_I = 2.4 \text{ V},$<br>1 mA < I <sub>O</sub> < I <sub>O</sub> (MAX)<br>$T_C = 25^{\circ}C$                 |                      | 0.003% |                      | /mA  |
|                           | Output line regulation                  |   | 2 V < V <sub>I</sub> < 3.3 V,<br>I <sub>O</sub> = 100 mA,<br>T <sub>C</sub> = 25°C                            |                      | 0.3%   |                      | /V   |
|                           | Short circuit current limit             |   | V <sub>I</sub> < 2.4 V, V <sub>O</sub> = 0 V,<br>T <sub>C</sub> = 25°C  |                      | 115    |                      | mA   |
| V(LBITRIP)                | Low battery trip voltage                | TPS60120, TPS60122,<br>TPS60124           | $V_I$ = 1.8 V to 2.2 V,<br>Hysteresis 0.8% for rising<br>LBI, $T_C$ = 0°C to 70°C                             | 1.15                 | 1.21   | 1.27                 | V    |
| I <sub>I(LBI)</sub>       | LBI input current                       | TPS60120, TPS60122,<br>TPS60124           | V <sub>(LBI)</sub> = 1.3 V  |                      |        | 100                  | nA   |
| V <sub>O(LBO)</sub>       | LBO output voltage low (see Note 2)     | TPS60120, TPS60122,<br>TPS60124           | V(LBI) = 0 V,<br>I(LBO,SINK) = 1 mA   |                      |        | 0.4                  | V    |
| llkg(LBO)                 | LBO leakage current                     | TPS60120, TPS60122, TPS60124              | V <sub>(LBI)</sub> = 1.3 V,<br>V <sub>(LBO)</sub> = 3.3 V   |                      | 0.01   | 0.1                  | μΑ   |

NOTE 2: During start-up the LBO and PG output signal is invalid for the first 500  $\mu s$ .



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electrical characteristics at C<sub>I</sub> = 10  $\mu$ F, C<sub>1F</sub> = C<sub>2F</sub> = 2.2  $\mu$ F, C<sub>O</sub> = 22  $\mu$ F, T<sub>C</sub> = -40°C to 85°C, V<sub>I</sub> = 2 V, V<sub>FB</sub> = V<sub>O</sub> and V<sub>(ENABLE)</sub> = V<sub>I</sub> (unless otherwise noted) (continued)

|                       | PARAMETER                                  |                                 | TEST CONDITIONS                                     | MIN          | TYP          | MAX                      | UNIT |
|-----------------------|--|---------------------------------|---|--------------|--------------|--------------------------|------|
| V(PGTRIP)             | Power-good trip voltage                    | TPS60121, TPS60123,<br>TPS60125 | $T_C = 0^{\circ}C$ to $70^{\circ}C$                 | 0.86 ×<br>VO | 0.90 ×<br>VO | 0.94 ×<br>V <sub>O</sub> | V    |
| V <sub>hys</sub> (PG) | Power-good trip voltage hysteresis         | TPS60121, TPS60123, TPS60125    | $V_O$ ramping negative,<br>$T_{CA} = 0$ °C to 70°C  |              | 0.8%         |                          |      |
| VO(PG)                | Power-good output voltage low (see Note 2) | TPS60121, TPS60123, TPS60125    | V <sub>O</sub> = 0 V, I <sub>(PG,SINK)</sub> = 1 mA |              |              | 0.4                      | V    |
| I <sub>lkg(PG)</sub>  | Power-good leakage current                 | TPS60121, TPS60123,<br>TPS60125 | $V_{O} = 3.3 \text{ V}, V_{(PG)} = 3.3 \text{ V}$   |              | 0.01         | 0.1                      | μА   |

NOTE 2: During start-up the LBO and PG output signal is invalid for the first  $500 \mu s$ .

### PARAMETER MEASUREMENT INFORMATION

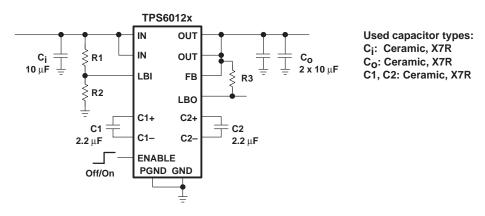


Figure 5. Circuit Used For Typical Characteristics Measurements

### TYPICAL CHARACTERISTICS

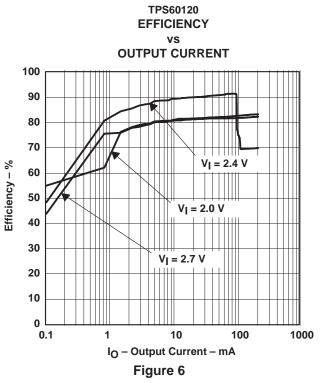
### **Table of Graphs**

|                 |                                 |  | FIGURE     |
|-----------------|---------------------------------|--|------------|
|                 | T#inionay                       | vs Output Current (TPS60120, TPS60122, and TPS60124) | 6, 7, 8    |
| П               | Efficiency                      | vs Input Voltage (TPS60120, TPS60122, and TPS60124)  | 9, 10, 11  |
| I               | Supply Current                  | vs Input Voltage                                     | 12         |
| Vo              | Output Voltage                  | vs Output Current (TPS60120, TPS60122, and TPS60124) | 13, 14, 15 |
| Vo              | Output Voltage                  | vs Input Voltage (TPS60120, TPS60122, and TPS60124)  | 16, 17, 18 |
| ٧o              | Output Voltage Ripple           | vs Time  | 19, 20, 21 |
| V <sub>PP</sub> | Output Voltage Ripple Amplitude | vs Input Voltage                                     | 22         |
| f(OSC)          | Oscillator Frequency            | vs Input Voltage                                     | 23         |
|                 | Load Transient Response         |  | 24         |
|                 | Line Transient Response         |  | 25         |
| VO              | Output Voltage                  | vs Time (Start-Up Timing)                            | 26         |



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### TYPICAL CHARACTERISTICS



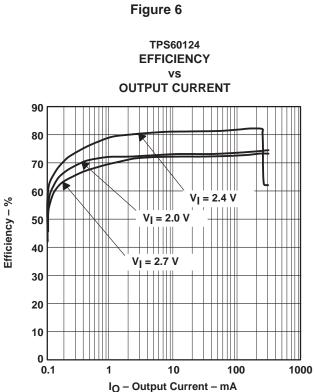
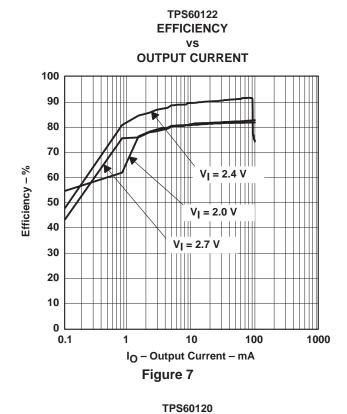
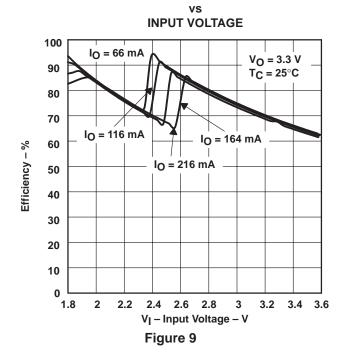


Figure 8



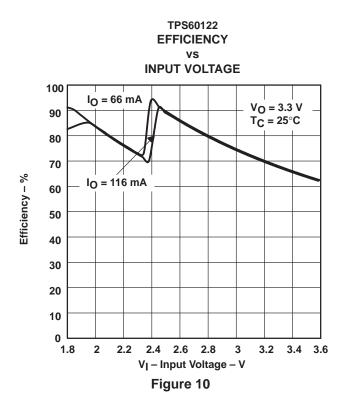
**EFFICIENCY** 

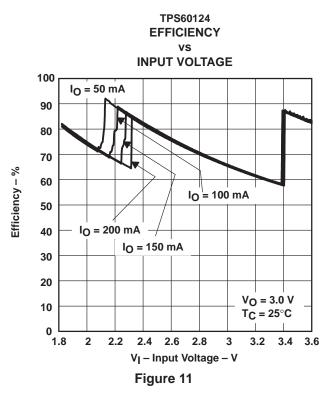


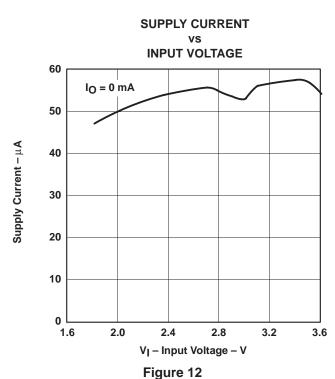


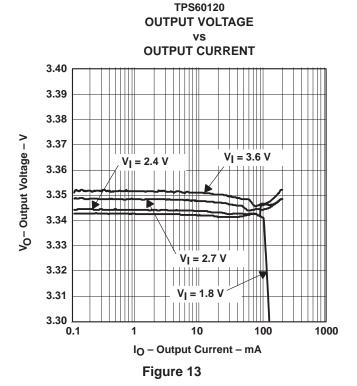
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### TYPICAL CHARACTERISTICS





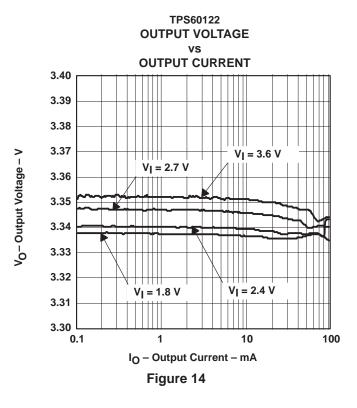


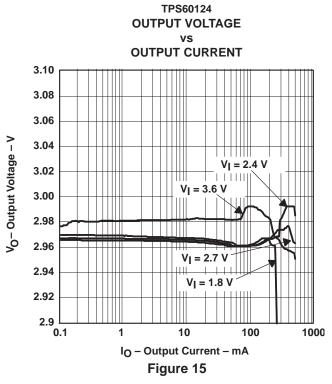


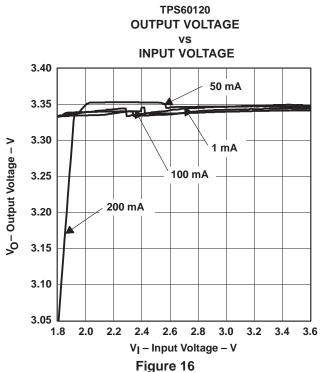


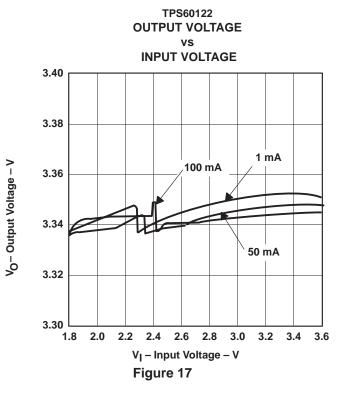
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### TYPICAL CHARACTERISTICS











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### TYPICAL CHARACTERISTICS

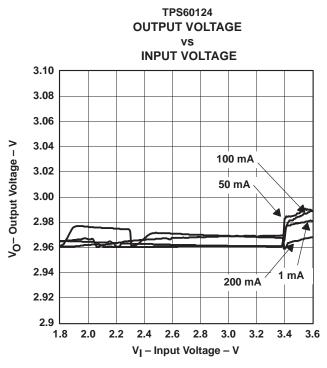


Figure 18

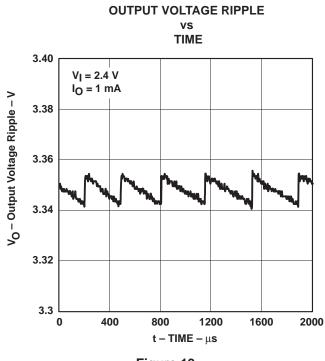
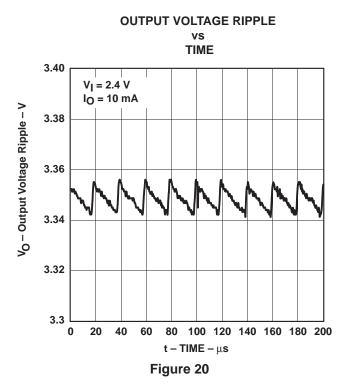
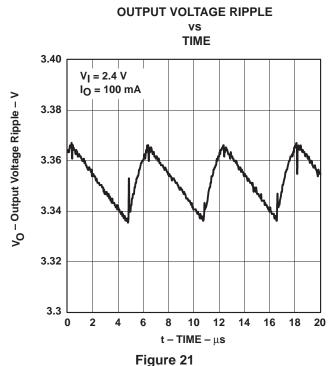


Figure 19

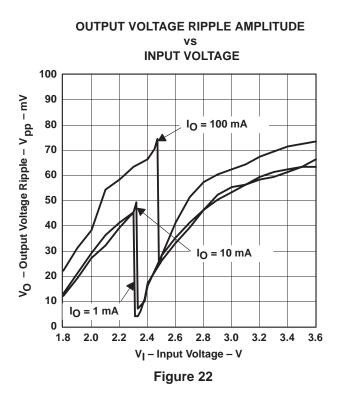


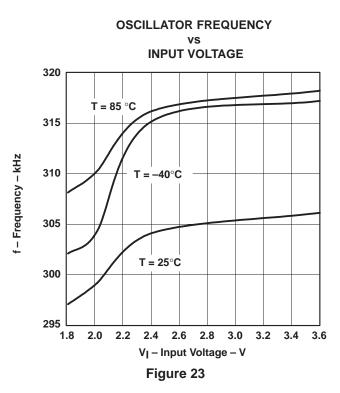


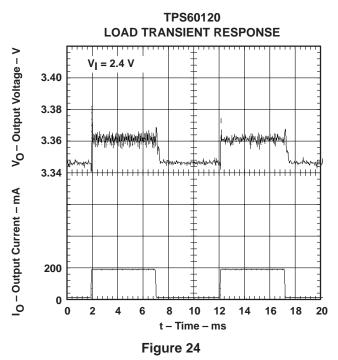


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### TYPICAL CHARACTERISTICS







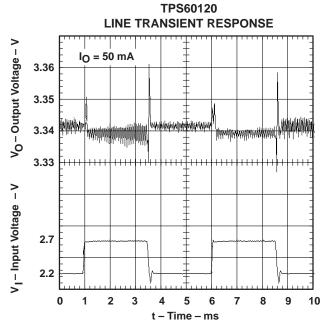


Figure 25

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### TYPICAL CHARACTERISTICS

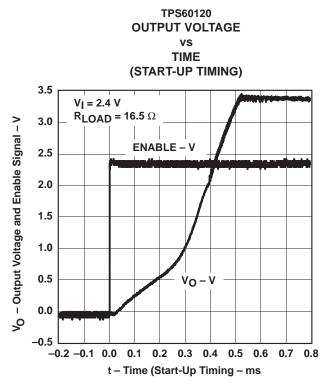


Figure 26

### **APPLICATION INFORMATION**

### capacitor selection

The TPS6012x charge pumps require only four external capacitors as shown in the basic application circuit. Their values and types are closely linked to the output current and output noise/ripple requirements. For lowest noise and ripple, low ESR ( $<0.1\ \Omega$ ) capacitors should be used for input and output capacitors.

The input capacitor improves system efficiency by reducing the input impedance. It also stabilizes the input current of the power source. The input capacitor should be chosen according to the power supply used and the distance from the power source to the converter IC. The input capacitor also has an impact on the output ripple requirements. The lower the ESR of the input capacitor  $C_i$ , the lower is the output ripple.  $C_i$  is recommended to be about two to four times as large as  $C_{(xF)}$ .

The output capacitor ( $C_O$ ) can be selected from 5-times to 50-times larger than  $C_{(XF)}$ , depending on the ripple tolerance. The larger  $C_O$  and the lower its ESR, the lower will be the output voltage ripple.  $C_i$  and  $C_O$  can be either ceramic or low-ESR tantalum; aluminum capacitors are not recommended.



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#### APPLICATION INFORMATION

### capacitor selection (continued)

Generally, the flying capacitors  $C_{(XF)}$  will be the smallest. Only ceramic capacitors are recommended because they are low ESR and because they retain their capacitance at the switching frequency. Because the device regulates the output voltage with the pulse-skip technique, a larger flying capacitor will lead to a higher output voltage ripple if the size of the output capacitor is not increased. Be aware that, depending on the material used to manufacture them, ceramic capacitors might lose their capacitance over temperature and voltage. Ceramic capacitors of type X7R or X5R material will keep their capacitance over temperature and voltage, whereas Z5U or Y5V-type capacitors will decrease in capacitance. Table 2 lists recommended capacitor values.

| PART VI IO (MA) |     | lo   | C <sub>i</sub><br>(μF) |                  | C <sub>(xF)</sub><br>(μF) | С <sub>о</sub><br>(µF) |                  | V <sub>PP</sub> TYP |
|-----------------|-----|------|------------------------|------------------|---------------------------|------------------------|------------------|---------------------|
|                 |     | (mA) | TANTALUM               | CERAMIC<br>(X7R) | CERAMIC<br>(X7R)          | TANTALUM               | CERAMIC<br>(X7R) | (mV)                |
| TPS60120        |     | 150  | 4.7                    | 4.7              | 2.2                       | 22                     | 4.7              | 65                  |
| TPS60121        | 2.4 |      |                        |                  |                           |                        | 22               | 40                  |
| TPS60124        | 2.4 | 200  | 10                     | 4.7              | 2.2                       | 22                     | 4.7              | 80                  |
| TPS60125        |     | 200  |                        | 10               | 2.2                       |                        | 22               | 35                  |
| TPS60122        | 2.4 | 50   |                        | 2.2              | 1                         |                        | 10               | 70                  |
| TPS60123        | 2.4 | 100  |                        | 4.7              | '                         |                        | 10               | 80                  |

**Table 2. Recommended Capacitor Values** 

The TPS6012x devices are charge pumps that regulate the output voltage using the pulse-skip operating mode. The output voltage ripple is therefore dependent on the values and the ESR of the input, output and flying capacitors. The only possibility to reduce the output voltage ripple is to choose the appropriate capacitors. The lowest output voltage ripple can be achieved with ceramic capacitors due to their low ESR and their frequency characteristic.

Ceramic capacitors typically have an ESR that is more than 10 times lower than tantalum capacitors and they retain their capacitance at frequencies more than 10 times higher than tantalum capacitors. Many different tantalum capacitors act as an inductance for frequencies higher than 200 kHz. This behavior increases the output voltage ripple. Therefore, the best choice for a minimized ripple is the ceramic capacitor. For applications that do not need higher performance in output voltage ripple, tantalum capacitors with a low ESR are a possibility for input and output capacitor, but a ceramic capacitor should be connected in parallel. Be aware that the ESR of tantalum capacitors is indirectly proportional to the physical size of the capacitor.

Table 2 is a good starting point for choosing the capacitors. If the output voltage ripple is too high for the application, it can be improved by selecting the appropriate capacitors. The first step is to increase the capacitance at the output. If the ripple is still too high, the second step would be to increase the capacitance at the input.

For the TPS60120, TPS60121, TPS60124, and TPS60125, the smallest board space can be achieved using Sprague's 595D-series tantalum capacitors for input and output. However, with the trend towards high capacitance ceramic capacitors in smaller size packages, these types of capacitors may become more competitive in size. The smallest size for the TPS60122 and TPS60123 can be achieved using the recommended ceramic capacitors.

Tables 3 and 4 lists the manufacturers of recommended capacitors. In most applications surface-mount tantalum capacitors will be the right choice. However, ceramic capacitors provide the lowest output voltage ripple due to their typically lower ESR.



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### **APPLICATION INFORMATION**

### capacitor selection (continued)

**Table 3. Recommended Capacitors** 

| MANUFACTURER | PART NUMBER     | CAPACITANCE | CASE SIZE | TYPE     |
|--------------|-----------------|-------------|-----------|----------|
| Taiyo Yuden  | LMK212BJ105KG-T | 1 μF        | 0805      | Ceramic  |
|              | LMK212BJ225MG-T | 2.2 μF      | 0805      | Ceramic  |
|              | LMK316BJ475KL-T | 4.7 μF      | 1206      | Ceramic  |
|              | LMK325BJ106MN-T | 10 μF       | 1210      | Ceramic  |
|              | LMK432BJ226MM-T | 22 μF       | 1812      | Ceramic  |
| AVX          | 0805ZC105KAT2A  | 1 μF        | 0805      | Ceramic  |
|              | 1206ZC225KAT2A  | 2.2 μF      | 1206      | Ceramic  |
|              | TPSC475035R0600 | 4.7 μF      | Case C    | Tantalum |
|              | TPSC106025R0500 | 10 μF       | Case C    | Tantalum |
|              | TPSC226016R0375 | 22 μF       | Case C    | Tantalum |
| Sprague      | 595D106X0016B2T | 10 μF       | Case B    | Tantalum |
|              | 595D226X06R3B2T | 22 μF       | Case B    | Tantalum |
|              | 595D226X0020C2T | 22 μF       | Case B    | Tantalum |
| Kemet        | T494C156K010AS  | 10 μF       | Case C    | Tantalum |
|              | T494C226M010AS  | 22 μF       | Case C    | Tantalum |

NOTE: Case code compatibility with EIA 535BAAC and CECC30801 molded chips.

**Table 4. Recommended Capacitor Manufacturers** 

| MANUFACTURER | CAPACITOR TYPE                               | INTERNET SITE           |
|--------------|--|-------------------------|
| Taiyo Yuden  | X7R/X5R ceramic                              | http://www.t-yuden.com/ |
| AVX          | X7R/X5R ceramic<br>TPS-series tantalum       | http://www.avxcorp.com/ |
| Sprague      | 595D-series tantalum<br>593D-series tantalum | http://www.vishay.com/  |
| Kemet        | T494-series tantalum                         | http://www.kemet.com/   |

### power dissipation

The power dissipated in the TPS6012x depends on output current and mode of operation (1.5x or doubler voltage conversion mode). It is described by the following:

$$\mathsf{P}_{DISS} = \left(\frac{1}{\eta} - 1\right) \mathsf{V}_{O} \times \mathsf{I}_{O} \ \ (\mathsf{Efficiency} \ \eta \ \mathsf{mainly} \ \mathsf{depends} \ \mathsf{on} \ \mathsf{V}_{I} \ \mathsf{and} \ \mathsf{also} \ \mathsf{on} \ \mathsf{I}_{O}. \ \mathsf{See} \ \mathsf{efficiency} \ \mathsf{graphs.})$$

P<sub>DISS</sub> must be less than that allowed by the package rating. See the absolute maximum ratings for 20-pin PWP package power-dissipation limits and deratings.



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#### APPLICATION INFORMATION

### board layout

Careful board layout is necessary due to the high transient currents and switching frequency of the converter. All capacitors should be soldered in close proximity to the IC. Connect ground and power ground pins through a short, low-impedance trace. A PCB layout proposal for a two-layer board is given in Figure 27. The bottom layer of the board carries only ground potential for best performance.

An evaluation module for the TPS60120 is available and can be ordered under product code TPS60120EVM–142. The EVM uses the layout shown in Figure 27. The layout also provides improved thermal performance as the exposed leadframe of the PowerPAD package can be soldered to the PCB.



Figure 27. Recommended PCB Layout for TPS6012X

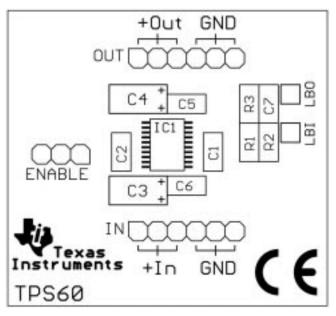


Figure 28. Component Placement

Table 5. Component Identification

| IC1    | TPS6012x                        |  |  |
|--------|---------------------------------|--|--|
| C1, C2 | Flying capacitors               |  |  |
| C3, C6 | Input capacitors                |  |  |
| C4, C5 | Output capacitors               |  |  |
| C7     | Stabilization capacitor for LBI |  |  |
| R1, R2 | Resistive divider for LBI       |  |  |
| R3     | Pullup resistor for LBO         |  |  |

The best performance of the converter is achieved with the additional bypass capacitors C5 and C6 at input and output. Capacitor C7 should be included if the large line transients are expected. The capacitors are not required. They can be omitted in most applications.



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### **APPLICATION INFORMATION**

### application proposals

### paralleling of two TPS6012x to deliver 400-mA total output current

Two TPS6012x devices can be connected in parallel to yield higher load currents. The circuit of Figure 29 can deliver up to 400 mA at an output voltage of 3.3 V. The devices can share the output capacitors, but each one requires its own transfer capacitors and input capacitor. If both a TPS60120 and a TPS60121 are used, it is possible to monitor the battery voltage with the TPS60120 using the low-battery comparator function and to supervise the output voltage with the TPS60121 using the power-good comparator. Make the layout of the charge pumps as similar as possible, and position the output capacitor the same distance from both devices.

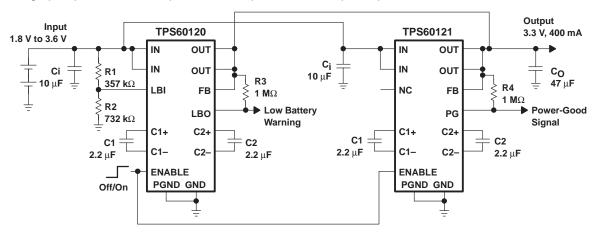


Figure 29. Paralleling of Two TPS6012x Charge Pumps



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#### APPLICATION INFORMATION

### TPS6012x operated with ultralow quiescent current

Because the output of the TPS6012x is isolated from the input when the devices are disabled, and because the internal resistive divider is disconnected in shutdown, an ultralow quiescent current mode can be implemented. In this mode, the output voltage is sustained because the converter is periodically enabled to refresh the output capacitor. The necessary external control signal that is applied to the ENABLE pin is generated from a microcontroller like the ultralow power microcontroller MSP430. For a necessary supply current for the system of 1 mA and a minimum supply voltage of 3 V with a 22- $\mu$ F output capacitor, the refresh has to be done after a maximum of 3.5 ms. Longer refresh periods can be achieved with a larger output capacitor.

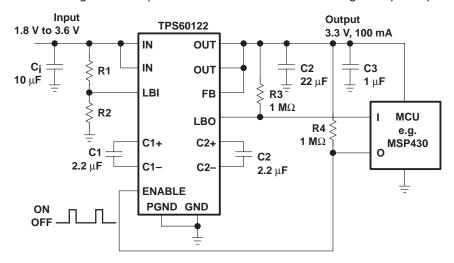


Figure 30. TPS60122 in UltraLow Quiescent Current Mode

#### regulated discharge of the output capacitors after disabling of the TPS6012x

During shutdown of the charge pump TPS6012x, the output is isolated from the input. Therefore, the discharging of the output capacitor depends on the load and on the leakage current of the capacitor. In certain applications it is necessary to completely remove the supply voltage from the load in shutdown mode. That means the output capacitor of the charge pump has to be actively discharged when the charge pump is disabled. Figure 31 shows one solution to this problem.

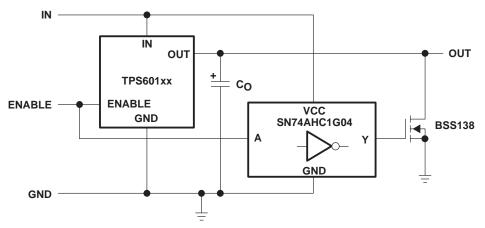


Figure 31. Block Diagram of the Regulated Discharge of the Output Capacitor



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### **APPLICATION INFORMATION**

### related information

### application reports

For more application information see:

- PowerPAD™ Application Report, Literature Number SLMA002
- TPS6010x/TPS6011x Charge Pump Application Report, Literature Number SLVA070
- Designer Note Page: Powering the TMS320C5420 Using the TPS60100, TPS76918, and the TPS3305-18, Literature Number SLVA082.

### device family products

Other devices in this family are:

| PART NUMBER | DATASHEET<br>LITERATURE<br>CODE | DESCRIPTION   |
|-------------|---------------------------------|---|
| TPS60100    | SLVS213B                        | Regulated 3.3-V, 200-mA low-noise charge pump dc-dc converter                                 |
| TPS60101    | SLVS214A                        | Regulated 3.3-V, 100-mA low-noise charge pump dc-dc converter                                 |
| TPS60110    | SLVS215A                        | Regulated 5-V, 300-mA low-noise charge pump dc-dc converter                                   |
| TPS60111    | SLVS216A                        | Regulated 5-V, 150-mA low-noise charge pump dc-dc converter                                   |
| TPS60130    | SLVS258                         | Regulated 5-V, 300-mA high efficiency charge pump dc-dc converter with low-battery comparator |
| TPS60131    | SLVS258                         | Regulated 5-V, 300-mA high efficiency charge pump dc-dc converter with power-good comparator  |
| TPS60132    | SLVS258                         | Regulated 5-V, 150-mA high efficiency charge pump dc-dc converter with low-battery comparator |
| TPS60133    | SLVS258                         | Regulated 5-V, 150-mA high efficiency charge pump dc-dc converter with power-good comparator  |



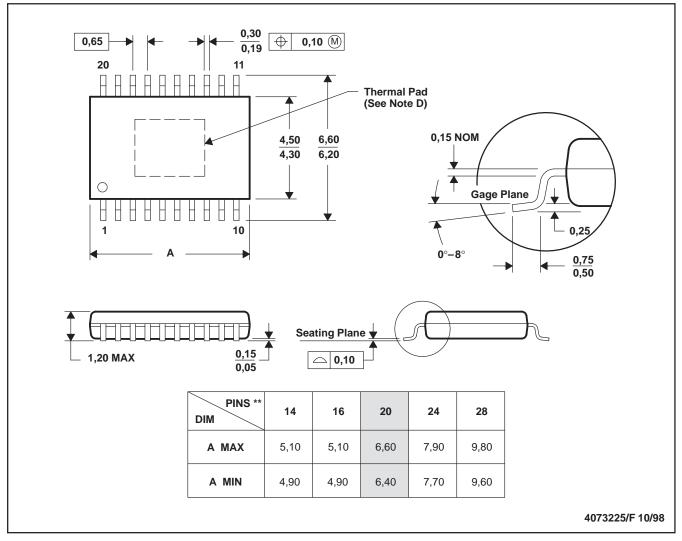
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### **MECHANICAL DATA**

### PWP (R-PDSO-G\*\*)

### 20 PINS SHOWN

### **PowerPAD™ PLASTIC SMALL-OUTLINE**

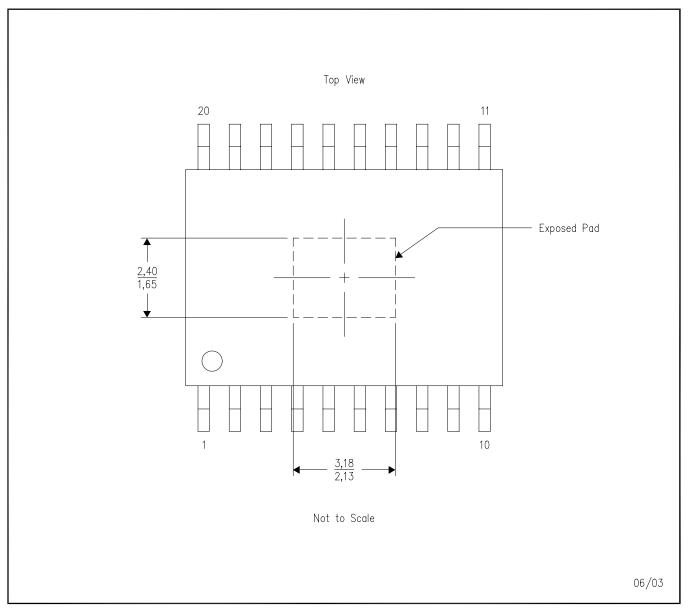


- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusions.
  - D. The package thermal performance may be enhanced by bonding the thermal pad to an external thermal plane. This pad is electrically and thermally connected to the backside of the die and possibly selected leads.
  - E. Falls within JEDEC MO-153



### PWP (R-PDSO-G20)

### **PowerPAD™ PLASTIC SMALL-OUTLINE**



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. For additional information on the PowerPAD™ package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.





8-Aug-2005

### **PACKAGING INFORMATION**

| Orderable Device | Status <sup>(1)</sup> | Package<br>Type | Package<br>Drawing | Pins | Package<br>Qty | e Eco Plan <sup>(2)</sup> | Lead/Ball Finish | MSL Peak Temp (3)   |
|------------------|-----------------------|-----------------|--------------------|------|----------------|---------------------------|------------------|---------------------|
| TPS60120PWP      | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60120PWPG4    | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60120PWPR     | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60120PWPRG4   | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60121PWP      | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60121PWPR     | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60121PWPRG4   | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60122PWP      | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60122PWPG4    | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60122PWPR     | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60122PWPRG4   | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60123PWP      | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60123PWPG4    | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60123PWPR     | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60123PWPRG4   | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60124PWP      | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60124PWPR     | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60124PWPRG4   | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60125PWP      | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60125PWPG4    | ACTIVE                | HTSSOP          | PWP                | 20   | 70             | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60125PWPR     | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |
| TPS60125PWPRG4   | ACTIVE                | HTSSOP          | PWP                | 20   | 2000           | Green (RoHS & no Sb/Br)   | CU NIPDAU        | Level-2-260C-1 YEAR |

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in

a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.



### PACKAGE OPTION ADDENDUM

8-Aug-2005

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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